

## Schottky Rectifier, 150 A


**ADD-A-PAK**

### PRODUCT SUMMARY

$I_{F(AV)}$	150 A
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### MECHANICAL DESCRIPTION

The Generation 5 of ADD-A-PAK module combine the excellent thermal performance obtained by the usage of direct bonded copper substrate with superior mechanical ruggedness, thanks to the insertion of a solid copper baseplate at the bottom side of the device.

The Cu baseplate allow an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improved thermal spread.

The Generation 5 of ADD-A-PAK module is manufactured without hard mold, eliminating in this way any possible direct stress on the leads.

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other Vishay HPP modules.

### FEATURES

- 175 °C  $T_J$  operation
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL pending
- Totally lead (Pb)-free, RoHS compliant
- Designed and qualified for industrial level


**RoHS**  
COMPLIANT

### DESCRIPTION

The VSKDS303.. Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	150	A
$V_{RRM}$		100	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	22 000	A
$V_F$	150 Apk, $T_J = 125 \text{ }^\circ\text{C}$	0.8	V
$T_J$	Range	- 55 to 175	$^\circ\text{C}$

### VOLTAGE RATINGS

PARAMETER	SYMBOL	VSKDS303/100P	UNITS
Maximum DC reverse voltage	$V_R$	100	V
Maximum working peak reverse voltage	$V_{RWM}$		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at $T_C = 96\text{ }^\circ\text{C}$ , rectangular waveform		300	A
				per module	
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	5 $\mu\text{s}$ sine or 3 $\mu\text{s}$ rect. pulse	Following any rated load condition and with rated $V_{RRM}$ applied	22 000	
		10 ms sine or 6 ms rect. pulse		2500	
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25\text{ }^\circ\text{C}$ , $I_{AS} = 5.5\text{ Amps}$ , $L = 1\text{ mH}$		15	mJ
Repetitive avalanche current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu\text{s}$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical		1	A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}^{(1)}$	150 A	$T_J = 25\text{ }^\circ\text{C}$	0.95	V
		300 A		1.28	
		150 A	$T_J = 125\text{ }^\circ\text{C}$	0.8	
		300 A		1.06	
Maximum reverse leakage current	$I_{RM}^{(1)}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	4.5	mA
$T_J = 125\text{ }^\circ\text{C}$	60				
Maximum junction capacitance	$C_T$	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		4150	pF
Typical series inductance	$L_S$	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	$dV/dt$	Rated $V_R$		10 000	V/ $\mu\text{s}$
RMS insulation voltage	$V_{INS}$	50 Hz, circuit to base, all terminals shorted (1 s)		3500	V

**Note**(1) Pulse width < 500  $\mu\text{s}$ 

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$			- 55 to 175	$^\circ\text{C}$
Maximum thermal resistance, junction to case per leg	$R_{thJC}$	DC operation		0.45	$^\circ\text{C/W}$
Maximum thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth and greased		0.1	
Approximate weight				110	g
				4	oz.
Mounting torque $\pm 10\%$	to heatsink			5	Nm
	busbar			4	
Case style		JEDEC		TO-240AA	

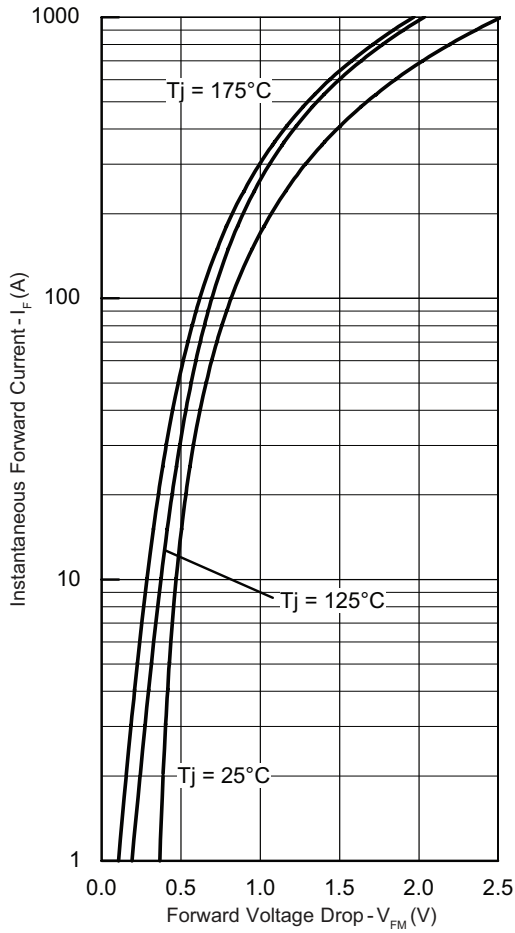


Fig. 1 - Maximum Forward Voltage Drop Characteristics

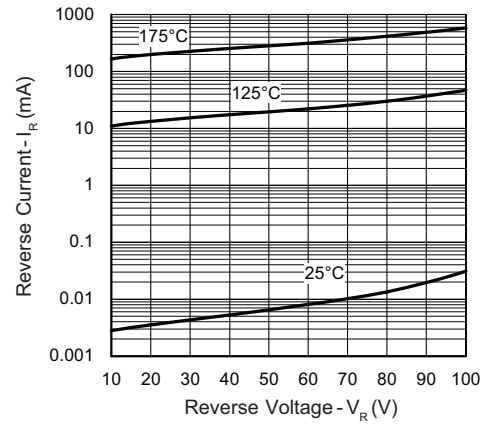


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

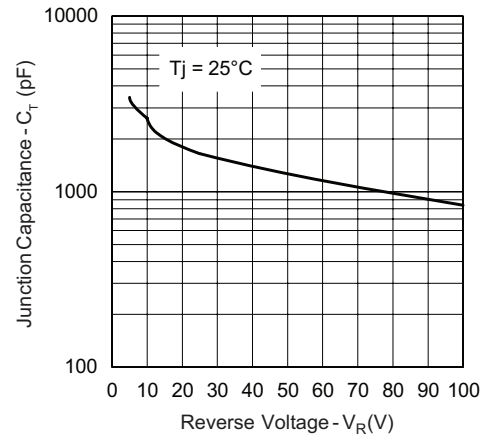


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

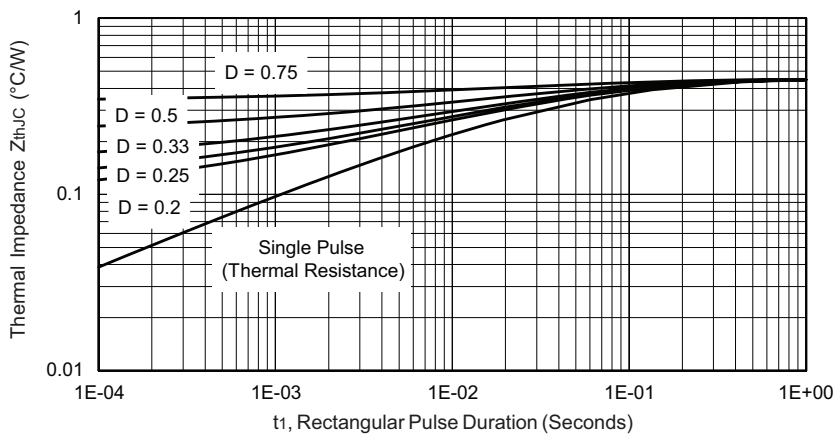


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

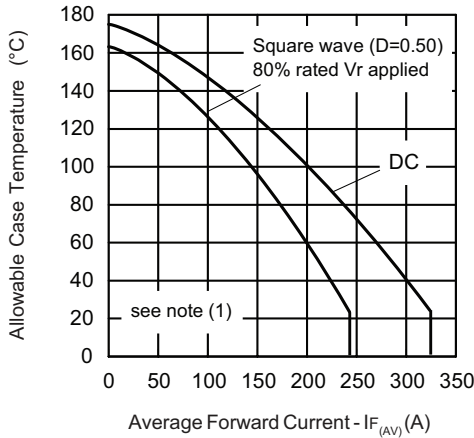


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

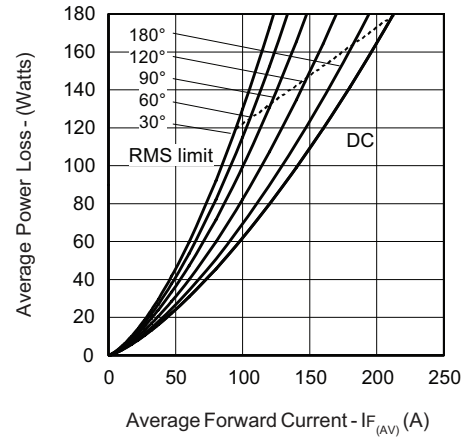


Fig. 6 - Forward Power Loss Characteristics

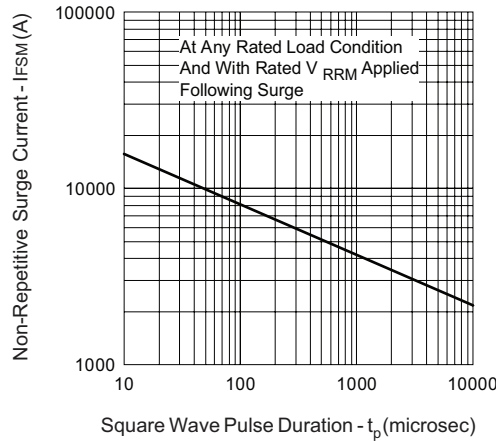


Fig. 7 - Maximum Non-Repetitive Surge Current

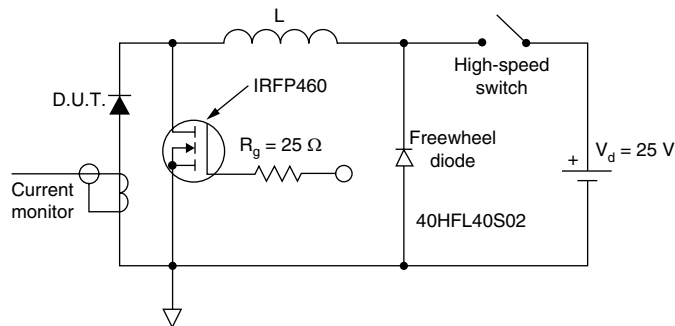


Fig. 8 - Unclamped Inductive Test Circuit

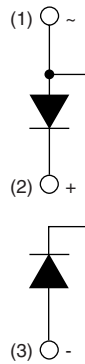
**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;
- $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);
- $P_{d_{REV}}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$

**ORDERING INFORMATION TABLE**

Device code	<b>VS</b>	<b>KD</b>	<b>S</b>	<b>30</b>	<b>3</b>	<b>/</b>	<b>100</b>	<b>P</b>
	①	②	③	④	⑤		⑥	⑦

- 1** - Vishay HPP
- 2** - Circuit configuration:  
KC = ADD-A-PAK - 2 diodes in series
- 3** - S = Schottky diode
- 4** - Average rating (x 10)
- 5** - Product silicon identification
- 6** - Voltage rating (100 = 100 V)
- 7** - Lead (Pb)-free

**CIRCUIT CONFIGURATION**

**LINKS TO RELATED DOCUMENTS**

Dimensions	<a href="http://www.vishay.com/doc?95174">http://www.vishay.com/doc?95174</a>
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